

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC74AC240P, TC74AC240F, TC74AC240FW, TC74AC240FT TC74AC244P, TC74AC244F, TC74AC244FW, TC74AC244FT

### Octal Bus Buffer

TC74AC240P/F/FW/FT Inverted, 3-State Outputs

TC74AC244P/F/FW/FT Non-Inverted, 3-State Outputs

Note: xxxFW (JEDEC SOP) is not available in Japan.

The TC74AC240 and 244 are advanced high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74AC240 is an inverting 3-state buffer while the 74AC244 is non-inverting. Both devices have two active-low output enables.

These devices are designed to be used in such applications as 3-state memory address drivers.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

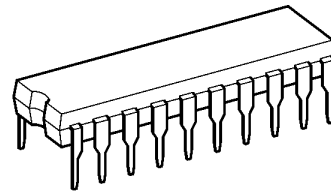
### Features

- High speed:  $t_{pd} = 4.0$  ns (typ.) at  $V_{CC} = 5$  V
- Low power dissipation:  $I_{CC} = 8$   $\mu$ A (max) at  $T_a = 25^\circ$ C
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min)  
Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC(opr)} = 2$  to 5.5 V
- Pin and function compatible with 74F240/244

#### Weight

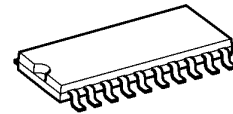
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

TC74AC240P, TC74AC244P

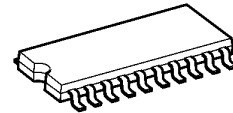


DIP20-P-300-2.54A

TC74AC240F, TC74AC244F

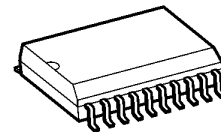


SOP20-P-300-1.27A



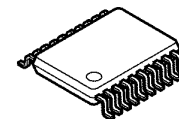
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TC74AC240FT, TC74AC244FT



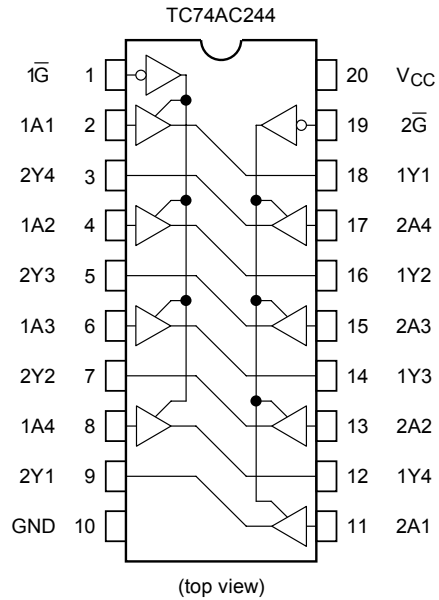
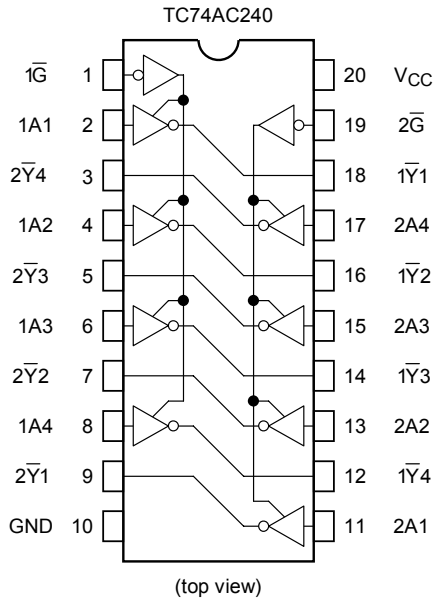
SOL20-P-300-1.27

TC74AC240FT, TC74AC244FT

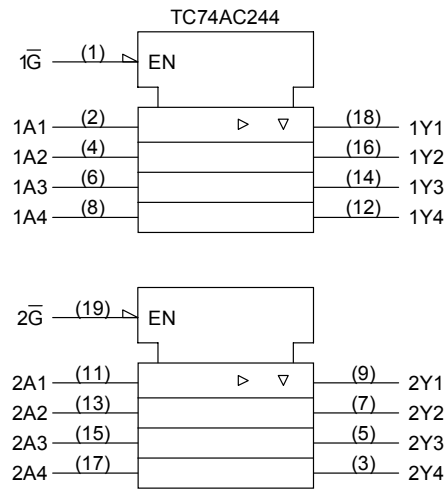
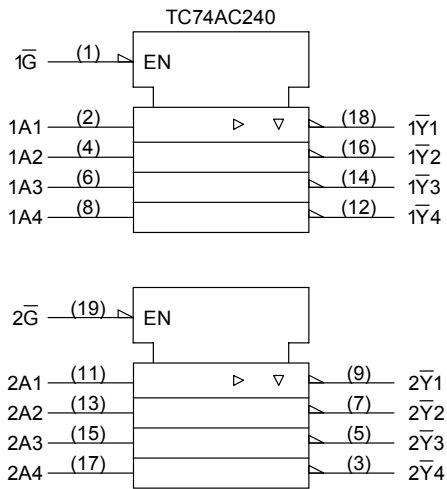


TSSOP20-P-0044-0.65A

## Pin Assignment



## IEC Logic Symbol



## Truth Table

Inputs		Outputs	
$\overline{G}$	A <sub>n</sub>	Y <sub>n</sub> (244)	$\overline{Y}_n$ (240)
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

## Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V
DC input voltage	$V_{IN}$	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	$\pm 20$	mA
Output diode current	$I_{OK}$	$\pm 50$	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 200$	mA
Power dissipation	$P_D$	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	$T_{stg}$	-65 to 150	$^{\circ}C$

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of  $T_a = -40$  to  $65^{\circ}C$ . From  $T_a = 65$  to  $85^{\circ}C$  a derating factor of  $-10$  mW/ $^{\circ}C$  should be applied up to 300 mW.

## Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2.0 to 5.5	V
Input voltage	$V_{IN}$	0 to $V_{CC}$	V
Output voltage	$V_{OUT}$	0 to $V_{CC}$	V
Operating temperature	$T_{opr}$	-40 to 85	$^{\circ}C$
Input rise and fall time	dt/dV	0 to 100 ( $V_{CC} = 3.3 \pm 0.3$ V) 0 to 20 ( $V_{CC} = 5 \pm 0.5$ V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40 to 85°C		Unit	
				Min	Typ.	Max	Min	Max		
High-level input voltage	V <sub>IH</sub>	—	2.0	1.50	—	—	1.50	—	V	
			3.0	2.10	—	—	2.10	—		
			5.5	3.85	—	—	3.85	—		
Low-level input voltage	V <sub>IL</sub>	—	2.0	—	—	0.50	—	0.50	V	
			3.0	—	—	0.90	—	0.90		
			5.5	—	—	1.65	—	1.65		
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I <sub>OH</sub> = -4 mA	3.0	2.58	—	—	2.48	—	
				4.5	3.94	—	—	3.80	—	
I <sub>OH</sub> = -75 mA (Note)	5.5	—	—	—	3.85	—				
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I <sub>OL</sub> = 12 mA	3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
I <sub>OL</sub> = 75 mA (Note)	5.5	—	—	—	—	1.65				
3-state output off-state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	5.5	—	—	±0.5	—	±5.0	μA	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	—	—	±0.1	—	±1.0	μA	
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	—	—	8.0	—	80.0	μA	

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

## AC Characteristics ( $C_L = 50 \text{ pF}$ , $R_L = 500 \text{ } \Omega$ , input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } 85^\circ\text{C}$		Unit
				Min	Typ.	Max	Min	Max	
Propagation delay time (Note 2)	$t_{pLH}$	—	$3.3 \pm 0.3$	—	6.3	10.5	1.0	12.0	ns
	$t_{pHL}$		$5.0 \pm 0.5$	—	4.8	7.0	1.0	8.0	
Propagation delay time (Note 3)	$t_{pLH}$	—	$3.3 \pm 0.3$	—	7.0	11.4	1.0	13.0	ns
	$t_{pHL}$		$5.0 \pm 0.5$	—	5.2	7.5	1.0	8.5	
Output enable time	$t_{pZL}$	—	$3.3 \pm 0.3$	—	8.4	14.0	1.0	16.0	ns
	$t_{pZH}$		$5.0 \pm 0.5$	—	5.9	8.7	1.0	10.0	
Output disable time	$t_{pLZ}$	—	$3.3 \pm 0.3$	—	6.4	10.5	1.0	12.0	ns
	$t_{pHZ}$		$5.0 \pm 0.5$	—	5.5	7.9	1.0	9.0	
Input capacitance	$C_{IN}$	—	—	5	10	—	10	pF	
Output capacitance	$C_{OUT}$	—	—	10	—	—	—	pF	
Power dissipation capacitance	$C_{PD}$	(Note 1)	—	30	—	—	—	pF	

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

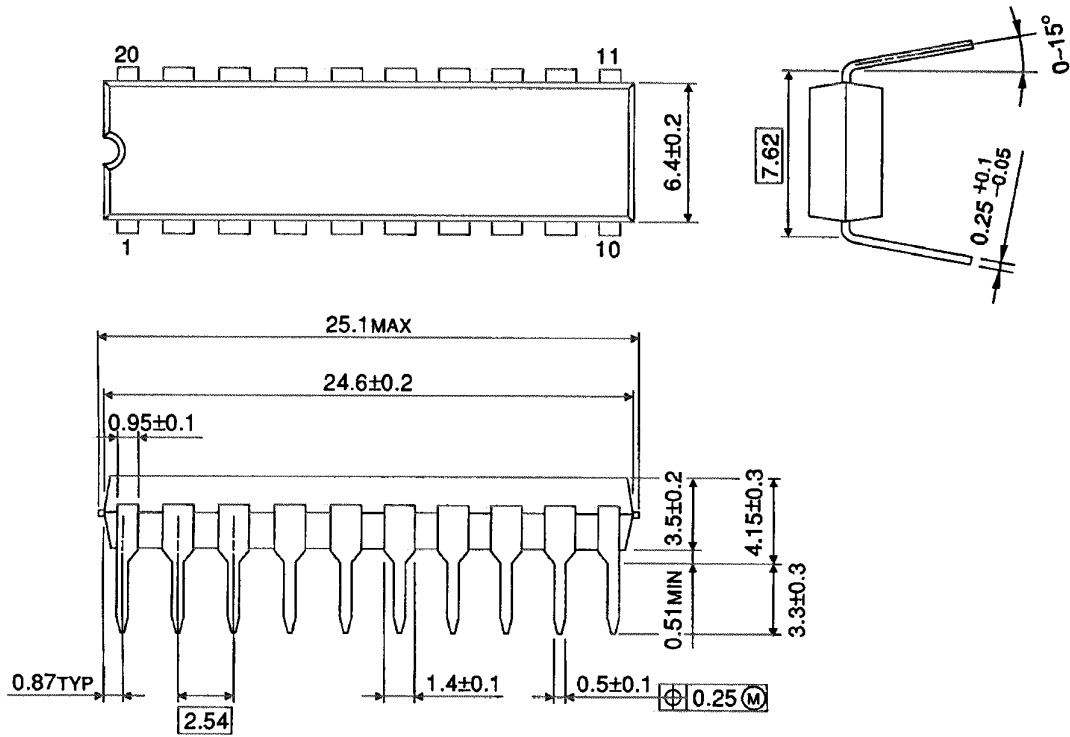
Note 2: For TC74AC240 only

Note 3: For TC74AC244 only

## Package Dimensions

DIP20-P-300-2.54A

Unit : mm

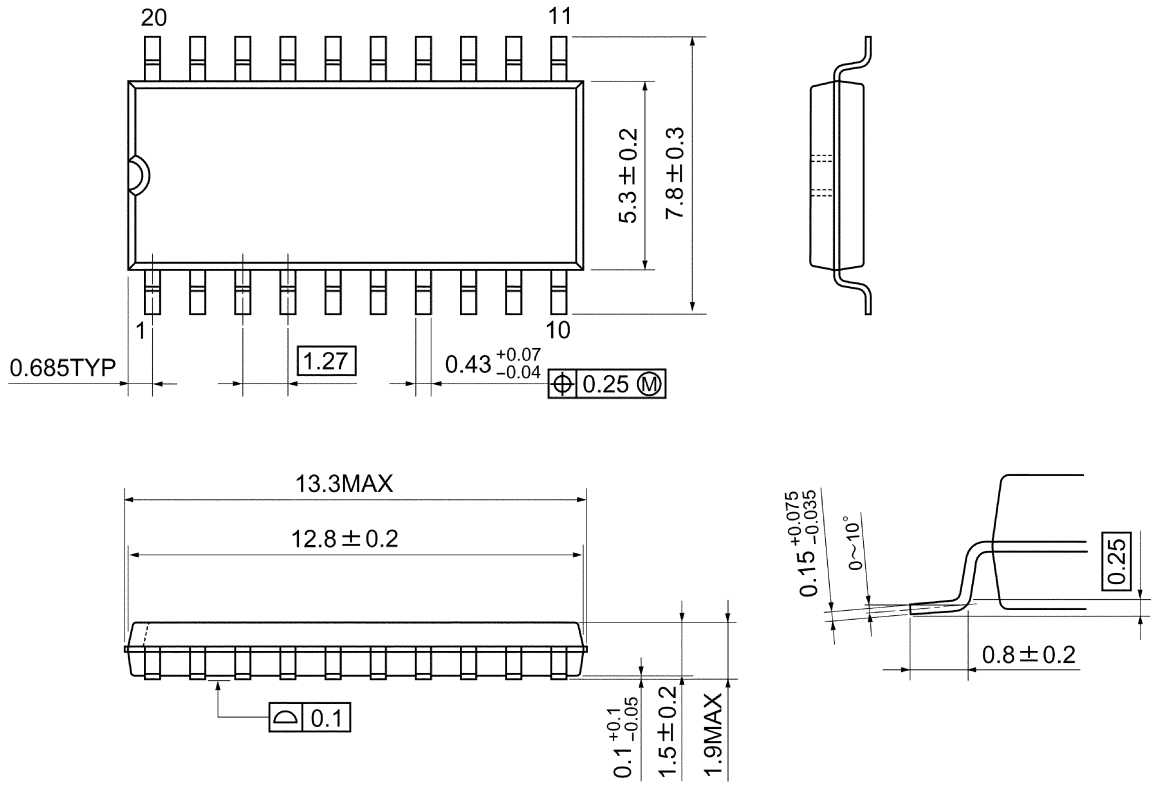


Weight: 1.30 g (typ.)

## Package Dimensions

SOP20-P-300-1.27A

Unit: mm

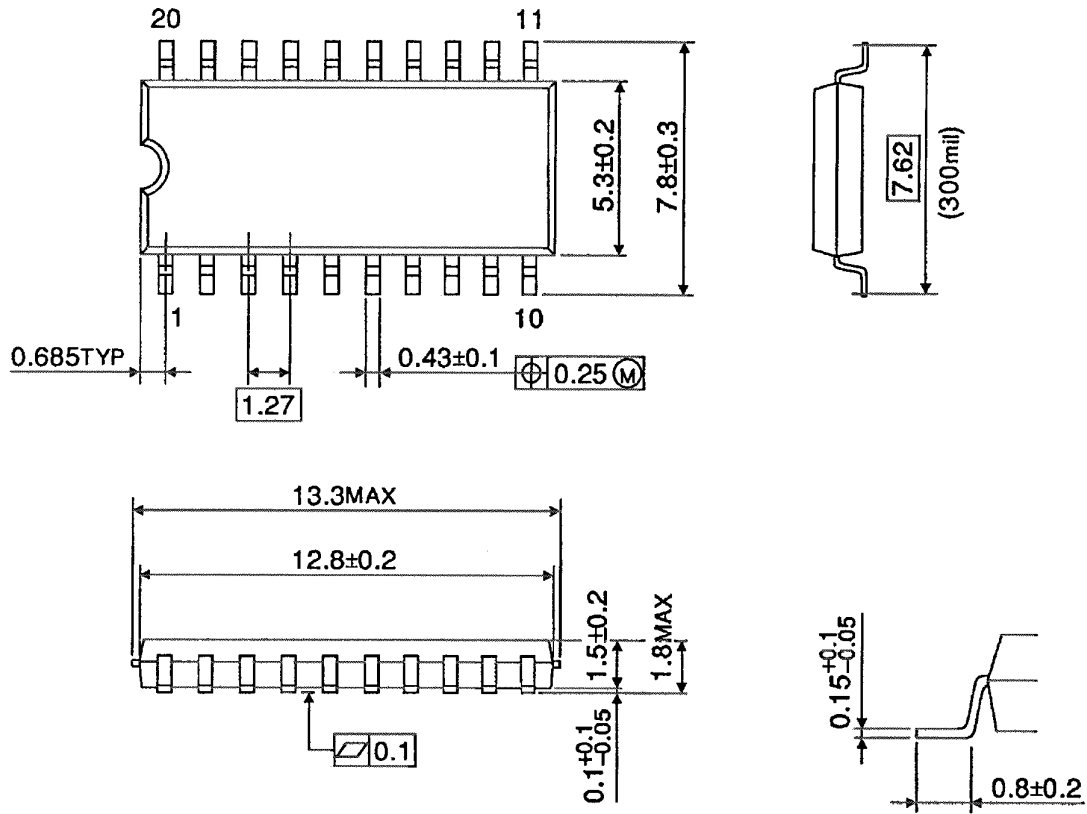


Weight: 0.22 g (typ.)

## Package Dimensions

SOP20-P-300-1.27

Unit : mm



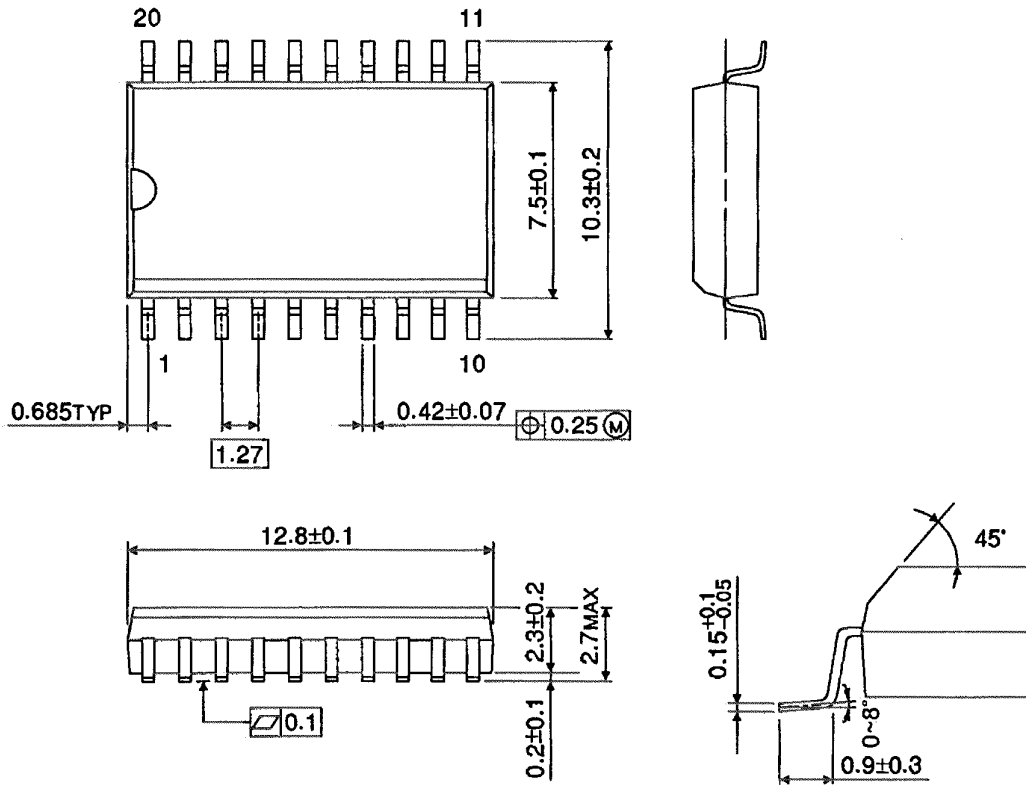
Weight: 0.22 g (typ.)



## Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



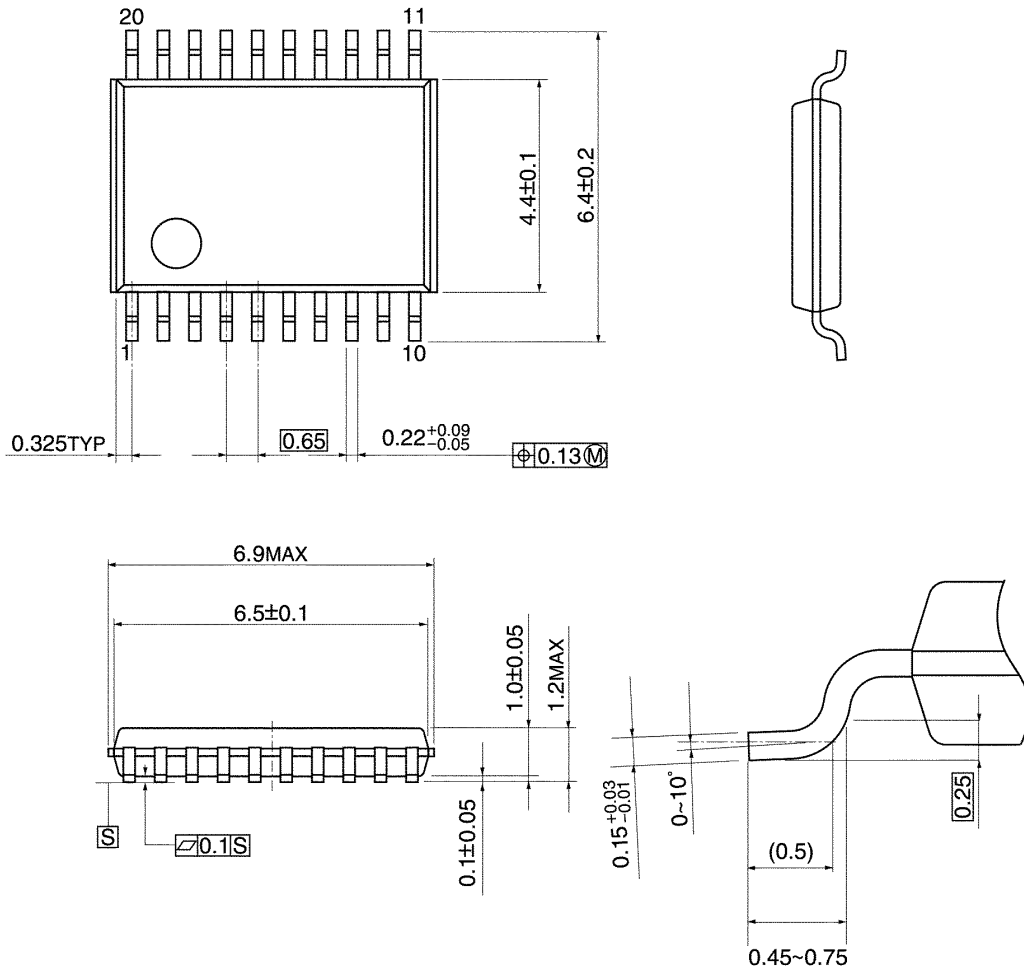
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

## Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

**Note: Lead (Pb)-Free Packages**

**DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A**

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